	Application No.	Applicant(s)	
	10/633,596	ZHONG ET AL.	/h
Notice of Allowability	Examiner	Art Unit	
	David S. Blum	2813	
The MAILING DATE of this communication appe All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in or other appropriate common GHTS. This application is s	n this application. If not include unication will be mailed in due of	d course. THIS
1. This communication is responsive to <u>11/11/05</u> .		•	
2. ☑ The allowed claim(s) is/are <u>4-10 and 13-17</u> .			
 3. Acknowledgment is made of a claim for foreign priority un a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 		or (f).	
. 2. Certified copies of the priority documents have	been received in Application	on No	
Copies of the certified copies of the priority doc	cuments have been receive	d in this national stage applicati	on from the
International Bureau (PCT Rule 17.2(a)).			
* Certified copies not received:			
Applicant has THREE MONTHS FROM THE "MAILING DATE" of noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		a reply complying with the req	uirements
4. A SUBSTITUTE OATH OR DECLARATION must be submit in INFORMAL PATENT APPLICATION (PTO-152) which give			OTICE OF
5. CORRECTED DRAWINGS (as "replacement sheets") mus	t be submitted.		
(a) \square including changes required by the Notice of Draftspers	on's Patent Drawing Reviev	v (PTO-948) attached	è
1) hereto or 2) to Paper No./Mail Date			
(b) ☐ including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or	in the Office action of	
Identifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the			back) of
6. DEPOSIT OF and/or INFORMATION about the depose attached Examiner's comment regarding REQUIREMENT F			ote the
<i>;</i>			
Attachment(s) 1. ☐ Notice of References Cited (PTO-892)	5. ☐ Notice of In	formal Patent Application (PTO	-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview S	ummary (PTO-413).	,
3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/0	Paper No./	/Mail Date Amendment/Comment	
Paper No./Mail Date 4.	8. 🛛 Examiner's	Statement of Reasons for Allov	vance
	9. 🗌 Other		

This action is in response to the amendment filed 11/11/05.

Reasons for Allowance

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- 1. Claims 4-6, 9-10, and 13-17 are allowed.
- 2. The following is an examiner's statement of reasons for allowance:

Claim 4 limits the method of modulating the flatband voltage to a plurality of anneals with a different anneal gas in each anneal. This limitation, in combination with the other limitations of claim 14 is not taught or suggested by the prior art of record. Lee (US 006844604B2) is silent as to the annealing gas or different gasses for annealing for N and P devices. Barile (US3793090) teaches annealing in oxygen to modulate the flatband voltage but does not teach or suggest multiple anneals with different gasses. That Barile anneals in oxygen may keep the N-channel device from exposure to N2, but not by a positive step in that annealing in oxygen does not preclude nitrogen from being a carrier gas and there are no positive steps to prevent exposure.

Claims 5-8 are allowed as being properly dependent upon allowed claim 4.

Claim 9 limits the step of modulating the flatband voltage to annealing for P-channel devices with N2. This limitation, in combination with the other limitations of claim 9 is not taught or suggested by the prior art of record. Lee (US 006844604B2) is silent as to

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modulating the flatband voltage to annealing for P-channel devices with N2. Barile (US3793090) teaches annealing in oxygen to modulate the flatband voltage modulating the flatband voltage to annealing for P-channel devices with N2. That Barile anneals in oxygen may keep the N-channel device from exposure to N2, but not by a positive step in that annealing in oxygen does not preclude nitrogen from being a carrier gas and there are no positive steps to prevent exposure.

Claim 10 is allowed as being properly dependent upon allowed claim 9.

Claims 13 limits the step of modulating the flatband voltage to preventing the N-channel device from exposure to N2 by masking. This limitation, in combination with the other limitations of claim 13 is not taught or suggested by the prior art of record. Lee (US 006844604B2) is silent as to modulating the flatband voltage to annealing for P-channel devices with N2. Barile (US3793090) teaches annealing in oxygen to modulate the flatband voltage modulating the flatband voltage to annealing for P-channel devices with N2. That Barile anneals in oxygen may keep the N-channel device from exposure to N2, but not by a positive step in that annealing in oxygen does not preclude nitrogen from being a carrier gas and there are no positive steps to prevent exposure.

Claims 14-17 are allowed as being properly dependent upon allowed claim 13.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to David S. Blum whose telephone number is (571)-272-1687) and e-mail address is David.blum@USPTO.gov.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr., can be reached at (571)-272-1702. Our facsimile number all patent correspondence to be entered into an application is (571) 273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

David S. Blum

November 21, 2005